

W40S01-04

SDRAM Buffer - 4 DIMM

Features

- Eighteen skew controlled CMOS outputs (SDRAM0:17)
- Supports four SDRAM DIMMs
- Ideal for high-performance systems designed around Intel®'s 440BX chip set
- I²C serial configuration interface
- Output skew between any two outputs is less than 250 ps
- 1 to 5 ns propagation delay
- DC to 133-MHz operation
- Single 3.3V supply voltage
- Low power CMOS design packaged in a 48-pin SSOP (Small Shrink Outline Package)

Overview

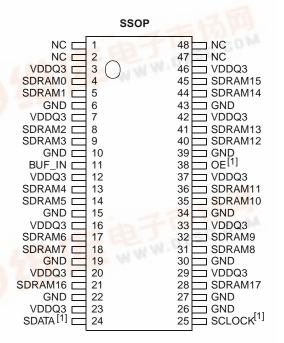
The Cypress W40S01-04 is a low-voltage, eighteen-output signal buffer. Output buffer impedance is approximately 15 Ω which is ideal for driving SDRAM DIMMs.

Key Specifications

Supply Voltages:	$V_{DDQ3} = 3.3V \pm 5\%$
Operating Temperature:	0°C to +70°C
Input Threshold:	1.5V typical
Maximum Input Voltage:	$V_{DDQ3} + 0.5V$
Input Frequency:	0 to 133 MHz
BUF_IN to SDRAM0:17 Propagation Dela	ay: 1.0 to 5.0 ns
Output Edge Rate:	<u>></u> 1.5 V/ns
Output Skew:	±250 ps
Output Duty Cycle:	45/55% worst case
Output Impedance:	15 ohms typical
Output Type:	CMOS rail-to-rail
Part to Part Skew:	700 ps

Block Diagram SDATA Serial Port Device Control OE SCLOCK SDRAM0 SDRAM1 SDRAM2 SDRAM3 SDRAM4 SDRAM5 SDRAM6 SDRAM7 SDRAM8 BUF_IN -SDRAM9 SDRAM10 SDRAM11 SDRAM12 SDRAM13 SDRAM14 SDRAM15 SDRAM16 SDRAM17

Pin Configuration



Note:

 Internal pull-up resistor of 250K on SDATA, SCLOCK, and OE inputs (not CMOS level).

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Pin Definitions

Pin Name	Pin No.	Pin Type	Pin Description
SDRAM0:17	4, 5, 8, 9, 13, 14, 17, 18, 21, 28, 31, 32, 35, 36, 40, 41, 44, 45	0	SDRAM Outputs: Provides buffered copy of BUF_IN. The propagation delay from a rising input edge to a rising output edge is 1 to 5 ns. All outputs are skew controlled to within ± 250 ps of each other.
BUF_IN	11	I	Clock Input: This clock input has an input threshold voltage of 1.5V (typ).
SDATA	24	I/O	$\it P^2C$ Data Input: Data should be presented to this input as described in the $\it I^2C$ section of this data sheet. Internal 250-kΩ pull-up resistor.
SCLOCK	25	I	$\it P^2C$ clock Input: The I 2 C data clock should be presented to this input as described in the I 2 C section of this data sheet. Internal 250-kΩ pull-up resistor.
VDDQ3	3,7,12,16, 20,23,29, 33,37,42, 46	Р	Power Connection: Power supply for core logic and output buffers. Connected to 3.3V supply.
GND	6, 10, 15, 19, 22, 26, 27, 30, 34, 39, 43	G	Ground Connection: Connect all ground pins to the common system ground plane.
OE	38	I	Output Enable: Internal 250-kΩ pull-up resistor. Three-states outputs when LOW.
NC	1, 2, 47, 48	-	No Connect: Do not connect.



Functional Description

Output Control Pins

Outputs three-stated when OE = 0, and toggle when OE = 1. Outputs are in phase with BUF_IN but are phase delayed by 1 to 5 ns. Outputs can also be controlled via the I²C interface.

Output Drivers

The W40S01-04 output buffers are CMOS type which deliver a rail-to-rail (GND to $\rm V_{\rm DD}$) output voltage swing into a nominal

capacitive load. Thus, output signaling is both TTL and CMOS level compatible. Nominal output buffer impedance is 15 ohms.

Operation

Data is written to the W40S01-04 in ten bytes of eight bits each. Bytes are written in the order shown in *Table 1*.

Table 1. Byte Writing Sequence

Byte Sequence	Byte Name	Bit Sequence	Byte Description
1	Slave Address	11010010	Commands the W40S01-04 to accept the bits in Data Bytes 0-6 for internal register configuration. Since other devices may exist on the same common serial data bus, it is necessary to have a specific slave address for each potential receiver. The slave receiver address for the W40S01-04 is 11010010. Register setting will not be made if the Slave Address is not correct (or is for an alternate slave receiver).
2	Command Code	Don't Care	Unused by the W40S01-04, therefore bit values are ignored (don't care). This byte must be included in the data write sequence to maintain proper byte allocation. The Command Code Byte is part of the standard serial communication protocol and may be used when writing to another addressed slave receiver on the serial data bus.
3	Byte Count	Don't Care	Unused by the W40S01-04, therefore bit values are ignored (don't care). This byte must be included in the data write sequence to maintain proper byte allocation. The Byte Count Byte is part of the standard serial communication protocol and may be used when writing to another addressed slave receiver on the serial data bus.
4	Data Byte 0	Refer to Table 2	The data bits in these bytes set internal W40S01-04 registers that control
5	Data Byte 1		device operation. The data bits are only accepted when the Address Byte bit sequence is 11010010, as noted above. For description of bit control
6	Data Byte 2		functions, refer to <i>Table 2</i> , Data Byte Serial Configuration Map.
7	Data Byte 3	Don't Care	Refer to Cypress clock drivers.
8	Data Byte 4		
9	Data Byte 5		
10	Data Byte 6		



Writing Data Bytes

Table 2 gives the bit formats for registers located in Data Bytes 0–6.

Each bit in the data bytes control a particular device function. Bits are written MSB (most significant bit) first, which is bit 7.

Table 2. Data Bytes 0–2 Serial Configuration Map^[2]

Affected Pin		cted Pin		Bit C	ontrol
Bit(s)	Pin No.	Pin Name	Control Function	0	1
Data Byte 0	SDRAM Acti	ve/Inactive Reg	ister (1=Enable, 0=Disable)		
7	18	SDRAM7	Clock Output Disable	Low	Active
6	17	SDRAM6	Clock Output Disable	Low	Active
5	14	SDRAM5	Clock Output Disable	Low	Active
4	13	SDRAM4	Clock Output Disable	Low	Active
3	9	SDRAM3	Clock Output Disable	Low	Active
2	8	SDRAM2	Clock Output Disable	Low	Active
1	5	SDRAM1	Clock Output Disable	Low	Active
0	4	SDRAM0	Clock Output Disable	Low	Active
Data Byte 1	SDRAM Acti	ve/Inactive Reg	ister (1=Enable, 0=Disable)	•	
7	45	SDRAM15	Clock Output Disable	Low	Active
6	44	SDRAM14	Clock Output Disable	Low	Active
5	41	SDRAM13	Clock Output Disable	Low	Active
4	40	SDRAM12	Clock Output Disable	Low	Active
3	36	SDRAM11	Clock Output Disable	Low	Active
2	35	SDRAM10	Clock Output Disable	Low	Active
1	32	SDRAM9	Clock Output Disable	Low	Active
0	31	SDRAM8	Clock Output Disable	Low	Active
Data Byte 2	SDRAM Acti	ve/Inactive Reg	ister (1=Enable, 0=Disable)		•
7	28	SDRAM17	Clock Output Disable	Low	Active
6	21	SDRAM16	Clock Output Disable	Low	Active
5	N/A	Reserved	(Reserved)		
4	N/A	Reserved	(Reserved)		
3	N/A	Reserved	(Reserved)		
2	N/A	Reserved	(Reserved)		
1	N/A	Reserved	(Reserved)		
0	N/A	Reserved	(Reserved)		

Note:

^{2.} At power-up all SDRAM outputs are enabled and active. Program Reserved bits to 0.



How To Use the Serial Data Interface

Electrical Requirements

Figure 1 illustrates electrical characteristics for the serial interface bus used with the W40S01-04. Devices send data over the bus with an open drain logic output that can (a) pull the bus line LOW, or (b) let the bus default to logic 1. The pull-up resistor on the bus (both clock and data lines) establish a default

logic 1. All bus devices generally have logic inputs to receive data.

Although the W40S01-04 is a receive-only device (no data write-back capability), it does transmit an "acknowledge" data pulse after each byte is received. Thus, the SDATA line can both transmit and receive data.

The pull-up resistor should be sized to meet the rise and fall times specified in AC parameters, taking into consideration total bus line capacitance.

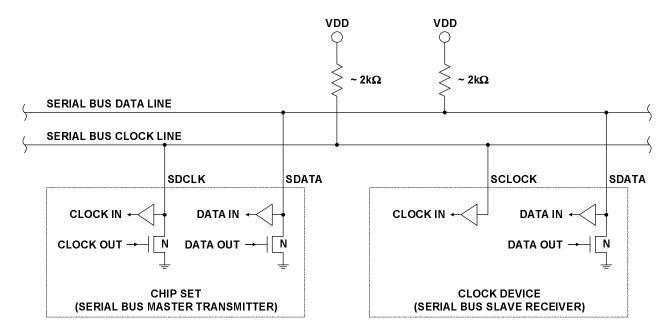


Figure 1. Serial Interface Bus Electrical Characteristics



Signaling Requirements

As shown in Figure 2, valid data bits are defined as stable logic 0 or 1 condition on the data line during a clock HIGH (logic 1) pulse. A transitioning data line during a clock HIGH pulse may be interpreted as a start or stop pulse (it will be interpreted as a start or stop pulse if the start/stop timing parameters are met).

A write sequence is initiated by a "start bit" as shown in *Figure* 3. A "stop bit" signifies that a transmission has ended.

As stated previously, the W40S01-04 sends an "acknowledge" pulse after receiving eight data bits in each byte as shown in *Figure 4*.

Sending Data to the W40S01-04

The device accepts data once it has detected a valid start bit and address byte sequence. Device functionality is changed upon the receipt of each data bit (registers are not double buffered). Partial transmission is allowed meaning that a transmission can be truncated as soon as the desired data bits are transmitted (remaining registers will be unmodified). Transmission is truncated with either a stop bit or new start bit (restart condition).

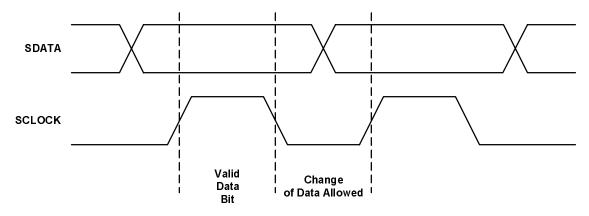


Figure 2. Serial Data Bus Valid Data Bit

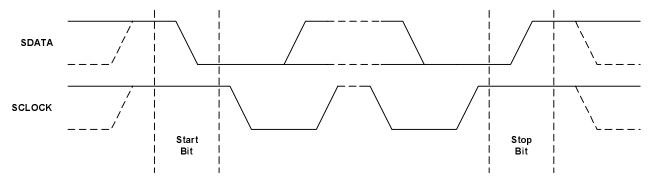


Figure 3. Serial Data Bus Start and Stop Bit



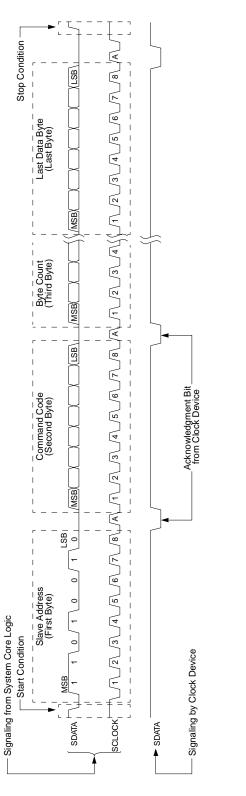


Figure 4. Serial Data Bus Write Sequence

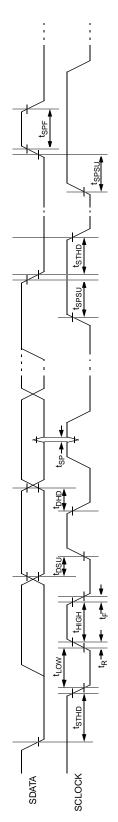


Figure 5. Serial Data Bus Timing Diagram



Absolute Maximum Ratings

Stresses greater than those listed in this table may cause permanent damage to the device. These represent a stress rating only. Operation of the device at these or any other conditions above those specified in the operating sections of this specification is not implied. Maximum conditions for extended periods may affect reliability

Parameter	Description	Rating	Unit
V_{DD} , V_{IN}	Voltage on any pin with respect to GND	-0.5 to +7.0	V
T _{STG}	Storage Temperature	-65 to +150	°C
T _A	Operating Temperature	0 to +70	°C
T _B	Ambient Temperature under Bias	−55 to +125	°C

DC Electrical Characteristics: $T_A = 0$ °C to +70°C, $V_{DDQ3} = 3.3V \pm 5\%$

Parameter	Description	Test Condition/ Comments	Min	Тур	Max	Unit
I _{DD}	3.3V Supply Current	BUF_IN = 100 MHz		320		mA
I _{DD Tristate}	3.3V Supply Current in Three-state	BUF_IN = 100 MHz		5		mA
Logic Inputs	(BUF_IN, OE, SCLOCK, SDATA)	•				
V _{IL}	Input Low Voltage		GND-0.3		0.8	V
V _{IH}	Input High Voltage		2.0		V _{DDQ3} +0.5	V
I _{ILEAK}	Input Leakage Current, BUF_IN		-5		+5	μA
I _{ILEAK}	Input Leakage Current ^[3]		-20		+5	μA
Logic Output	s (SDRAM0:17) ^[4]					
V _{OL}	Output Low Voltage	I _{OL} = 1 mA			50	mV
V _{OH}	Output High Voltage	I _{OH} = -1 mA	3.1			V
I _{OL}	Output Low Current	V _{OL} = 1.5V	70	110	185	mA
I _{OH}	Output High Current	V _{OH} = 1.5V	65	100	160	mA
Pin Capacitar	nce/Inductance		•			•
C _{IN}	Input Pin Capacitance (Except BUF_IN)				5	pF
C _{OUT}	Output Pin Capacitance				6	pF
L _{IN}	Input Pin Inductance				7	nΗ

Notes:

^{3.} OE, SCLOCK, and SDATA logic pins have a 250-k Ω internal pull-up resistor (not CMOS level). 4. Outputs loaded by 6" 60Ω transmission lines with 20-pF capacitors.



$\textbf{AC Electrical Characteristics:} \ \, T_{A} = \underbrace{0^{\circ}\text{C to +70^{\circ}\text{C}}, \, V_{DDQ3} = 3.3V \pm 5\% \, \, \text{(Lump Capacitance Test Load = 30 pF)}}$

Parameter	Description	Test Condition	Min	Тур	Max	Unit
f _{IN}	Input Frequency		0		133	MHz
t _R	Output Rise Edge Rate	Measured from 0.4V to 2.4V	1.5		4.0	V/ns
t _F	Output Fall Edge Rate	Measured from 2.4V to 0.4V	1.5		4.0	V/ns
t _{SR}	Output Skew, Rising Edges				250	ps
t _{SF}	Output Skew, Falling Edges				250	ps
t _{EN}	Output Enable Time		1.0		8.0	ns
t _{DIS}	Output Disable Time		1.0		8.0	ns
t _{PR}	Rising Edge Propagation Delay		1.0		5.0	ns
t _{PF}	Falling Edge Propagation Delay		1.0		5.0	ns
t _D	Duty Cycle	Measured at 1.5V	45		55	%
Z _o	AC Output Impedance			15		Ω
T _{SPP}	Part to Part Skew				700	ps

Ordering Information

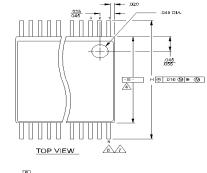
Ordering Code	Freq. Mask Code	Package Name	Package Type
W40S01	04	Н	48-pin SSOP (300 mils)

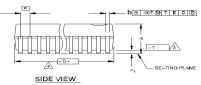
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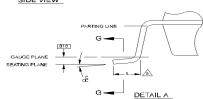


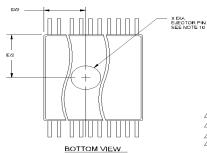
Package Diagram

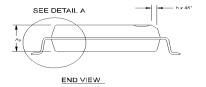
48-Pin Shrink Small Outline Package (SSOP, 0.300 inch)

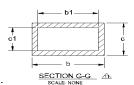












NOTES:

- MAXIMUM DIE THICKNESS ALLOWABLE IS .025.

S		COMMO	V		NOTE		4		6
M B	D	IMENSIO	NS .	N _O	VARI-		D		N
9	MIN.	NOM.	MAX.	١.	ATIONS	MIN.	NOM.	MAX.	
Α	.095	.102	.110		AA	.620	.625	.630	48
A ₁	.008	.012	.016		AB	.720	.725	.730	56
A	.088	.090	.092						
b	.008	.010	.0135		THE TABLE IN INCLE				
b₁	.008	.010	.012		THIS TABLE IN INCHE				
С	.005	-	.010						
C ₁	.005	.006	.0085						
D	SEE	VARIATION	IS	4					
E	.292	.296	.299						
е		.025 BSC							
H	.400	.406	.410						
h	.010	.013	.016						
L	.024	.032	.040						
N	SEE VARIATIONS			6					
X &	.085	.093	.100	10					
œ	0°	5°	8°						

S		COMMO	N		NOTE		4		6
M	D	IMENSIO	NS	١,٥	VARI-			N	
1 %	MIN.	NOM.	MAX.	, F	ATIONS	MIN.	NOM.	MAX.	
Α	2.41	2.59	2.79		AA	15.75	15.88	16.00	48
A,	0.20	0.31	0.41		AB	18.29	18.42	18.54	56
A.	2.24	2.29	2.34						
b	0.203	0.254	0.343			T T			
b ₁	0.203	0.254	0.305			THIS TAI	BLE IN N	IILLIME I	ERS
С	0.127	-	0.254						
C-	0.127	0.152	0.216						
D	SEE	VARIATION		4					
E	7.42	7.52	7.59						
е		0.635 BSC							
H	10.16	10.31	10.41						
h	0.25	0.33	0.41						
L	0.61	0.81	1.02						
N	SEE VARIATIONS			6					
X		2.36	2.54	10					
ર્લ્ટ	0°	5°	8°						